

GPB5551 Transistor(NPN)

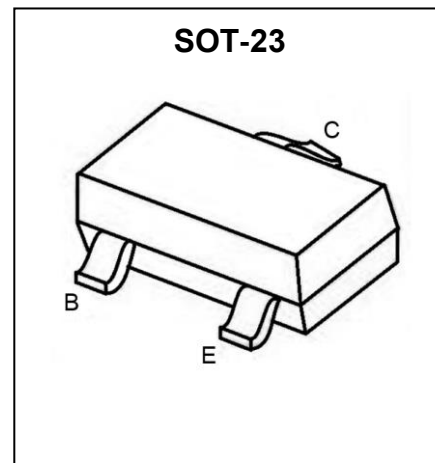
Feature

- Switching Transistor

Marking: G1

MAXIMUM RATINGS (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current -Continuous	I _C	0.6	A
Power Dissipation	P _d	0.3	W
Junction Temperature	T _J	150	℃
Storage Temperature	T _{STG}	-55~ +150	℃



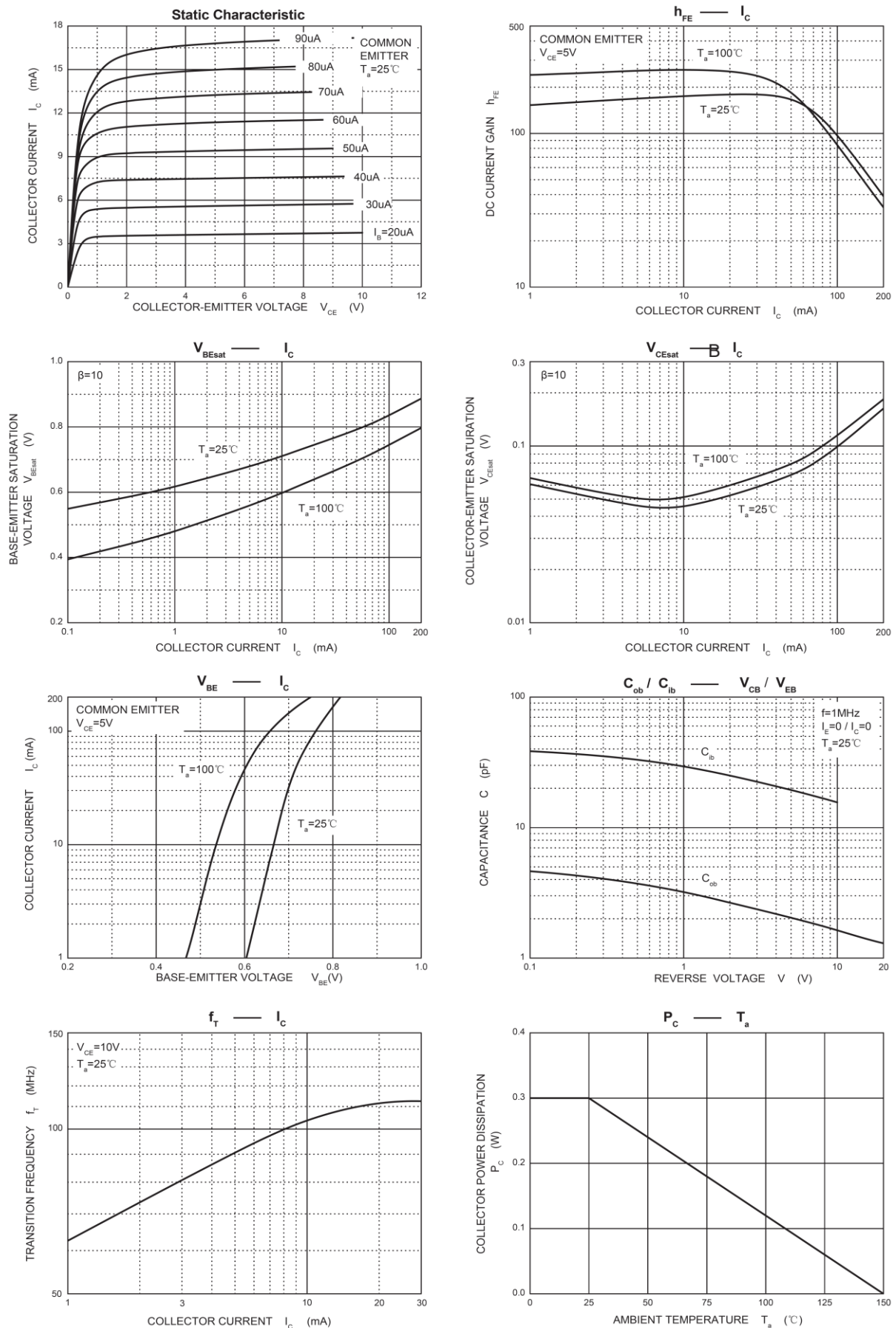
Classification of h_{FE3}

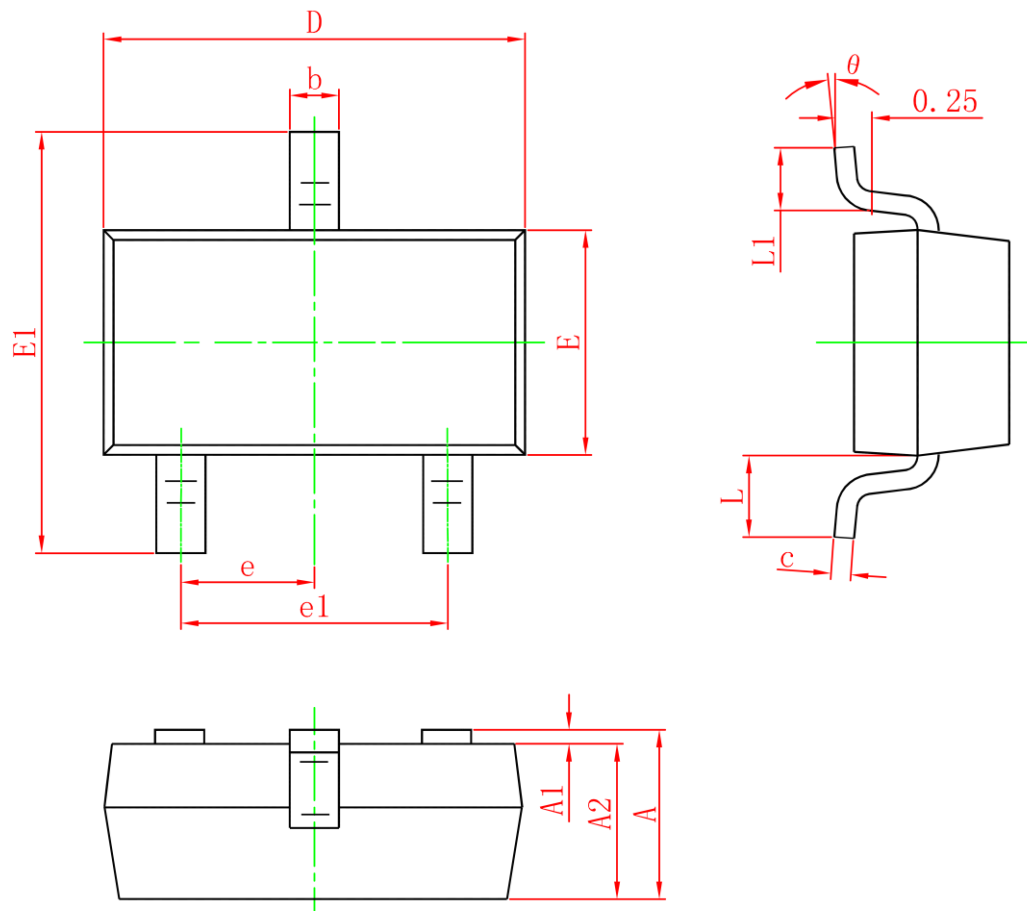
Rank	L	H
Range	100-200	200-300

ELECTRICAL CHARACTERISTICS(T_A=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Max	Unit
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C = 100μA, I _E = 0	180		V
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = 1mA, I _B = 0	160		V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 100μA, I _C = 0	5		V
Collector Cut-Off Current	I _{CBO}	V _{CB} = 150V, I _E = 0		0.1	μA
Collector Cut-Off Current	I _{CEO}	V _{CE} = 150V, I _B = 0		0.1	μA
Emitter Cut-Off Current	I _{EBO}	V _{EB} = 4V, I _C = 0		0.1	μA
DC Current Gain	h _{FE1}	V _{CE} = 5V, I _C = 0.1mA	10		
	h _{FE2}	V _{CE} = 5V, I _C = 1mA	10		
	h _{FE3}	V _{CE} = 5V, I _C = 10mA	100	300	
	h _{FE4}	V _{CE} = 5V, I _C = 50mA	40		
	h _{FE5}	V _{CE} = 5V, I _C = 100mA	30		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C = 10mA, I _B = 1mA		0.2	V
		I _C = 50mA, I _B = 5mA		0.3	V
Base-Emitter Saturation Voltage	V _{BE(sat)}	I _C = 10mA, I _B = 1mA		1.1	V
		I _C = 50mA, I _B = 5mA		1.2	V
Transition Frequency	f _T	V _{CE} = 6V, I _C = 10mA, f = 100MHz	100		MHZ
Input Capacitance	C _{IB}	V _{CB} = 6V, I _E = 0, f = 1MHz		4.0	pF
Out Capacitance	C _{OB}	V _{EB} = 0.5V, I _C = 0, f = 1MHz		8.0	pF

Typical Characteristics



SOT-23 Package Information


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0	0.100	0	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.150	1.500	0.045	0.059
E1	2.250	2.650	0.089	0.104
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

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